



Schottky Barrier Diode

Features

1. Small surface mounting type.
2. High reliability.
3. Low reverse current and low forward voltage.
4. This diode is also available in the DO-35 case with type designation SD101A, B, C.



Applications

HF-Detector, protection circuit, small battery charger, power supplies, DC/DC converter for notebooks, etc.

Absolute Maximum Ratings

$T_j=25^{\circ}\text{C}$

Parameter	Test Conditions	Type	Symbol	Value	Unit
Peak inverse voltage		LL101A	V_{RRM}	60	V
		LL101B	V_{RRM}	50	V
		LL101C	V_{RRM}	40	V
Maximum single cycle surge 10 μS square wave			I_{FSM}	2	A
Power dissipation	$T_{amb}=25^{\circ}\text{C}$		P_V	400	mW
Storage temperature range			T_{stg}	-55~+150	$^{\circ}\text{C}$

Stresses exceeding maximum ratings may damage the device. Maximum ratings are stress ratings only. Functional operation above the recommended operating conditions is not implied. Extended exposure to stresses above the recommended operating conditions may affect device reliability.



Electrical Characteristics

$T_j = 25^\circ\text{C}$

Parameter	Test Conditions	Type	Symbol	Min	Typ	Max	Unit
Forward voltage drop	$I_F = 1\text{mA}$	LL101A	V_F			0.41	V
		LL101B				0.4	
		LL101C				0.39	
	$I_F = 15\text{mA}$	LL101A	V_F			1	V
		LL101B				0.95	
		LL101C				0.9	
Leakage current	$V_R = 50\text{V}$	LL101A	I_R			0.2	μA
	$V_R = 40\text{V}$	LL101B				0.2	
	$V_R = 30\text{V}$	LL101C				0.2	
Junction capacitance	$V_R = 0\text{V}, f = 1\text{MHz}$	LL101A	C_{tot}			2.0	pF
		LL101B				2.1	
		LL101C				2.2	
Reverse recovery time	$I_F = I_R = 5\text{mA to } 0.1I_R$		t_{rr}			1	ns

Characteristics ($T_j = 25^\circ\text{C}$)

$^\circ\text{C}$ unless otherwise specified)

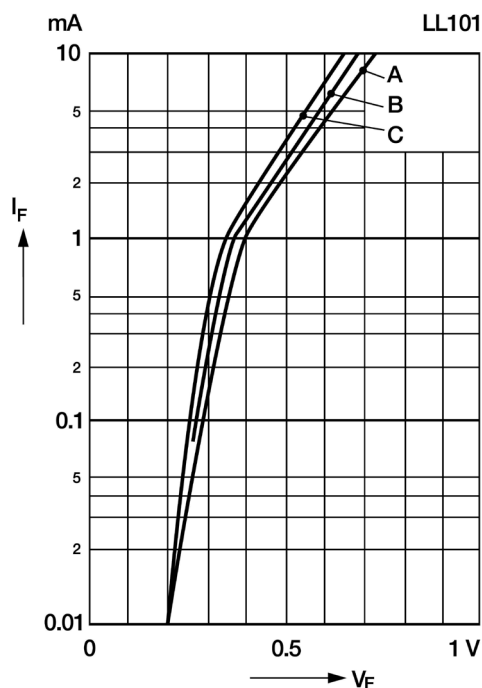


Figure 1. Typ. I_F vs. V_F for primary conduction through the Schottky barrier

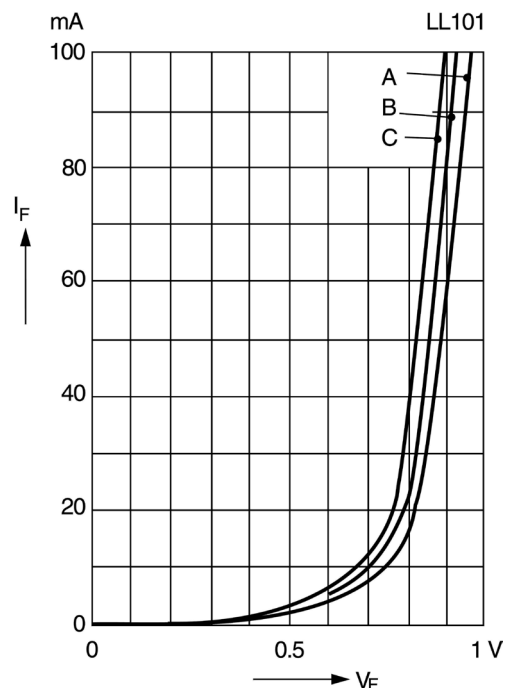


Figure 2. Typ. I_F of combination Schottky barrier and PN junction guard ring

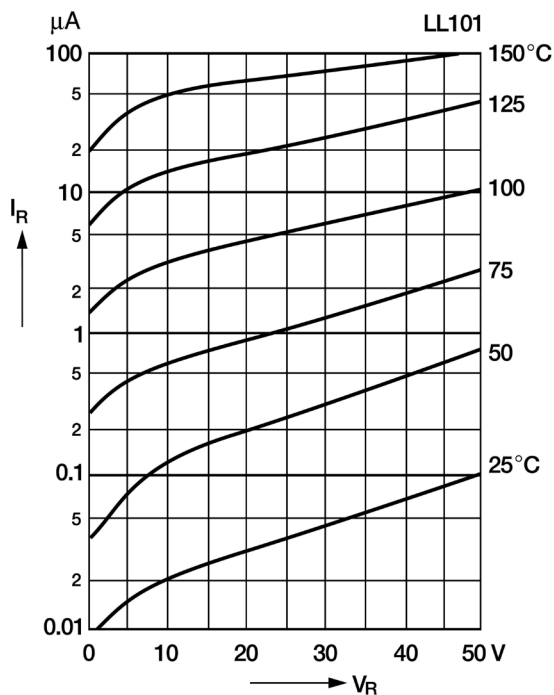


Figure 3. Typical variation of reverse current at various temperatures

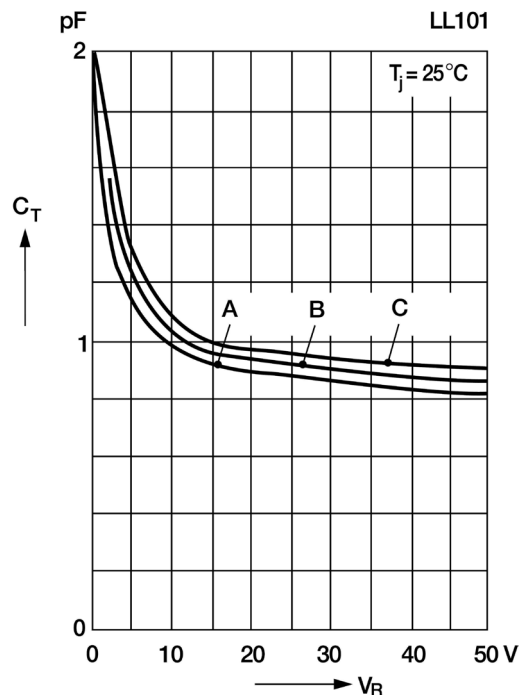
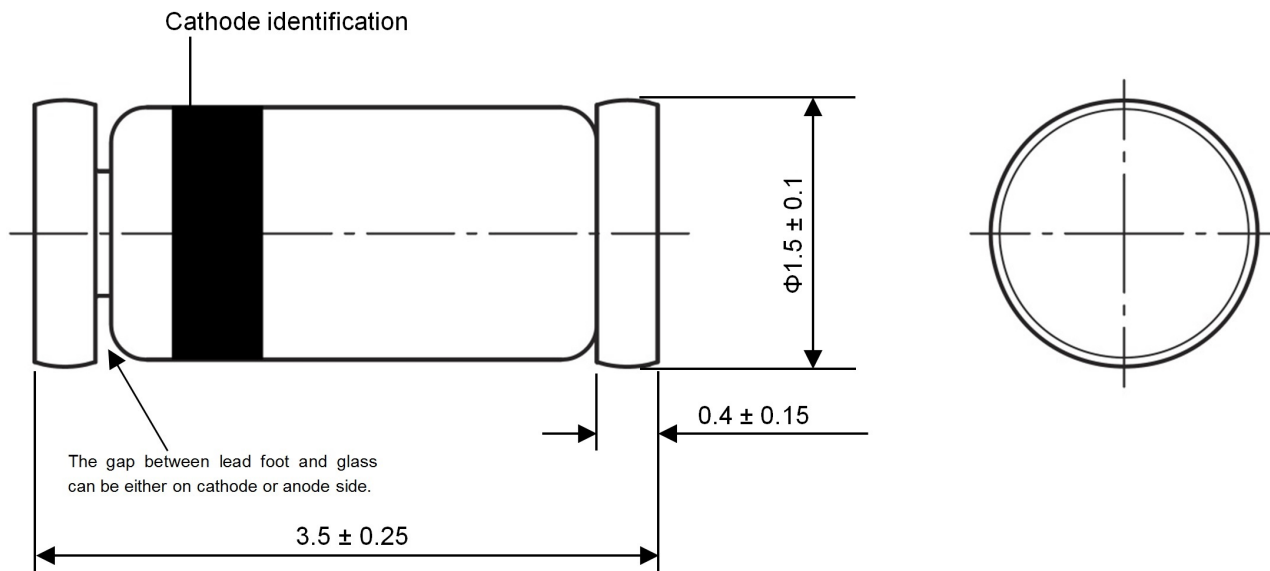


Figure 4. Typical capacitance curve as a function of reverse voltage

Dimensions in mm



Glass Case
Mini Melf / SOD-80
JEDEC DO-213 AA

Excel Semiconductor